



2SK2624LS

Ultrahigh-Speed Switching Applications

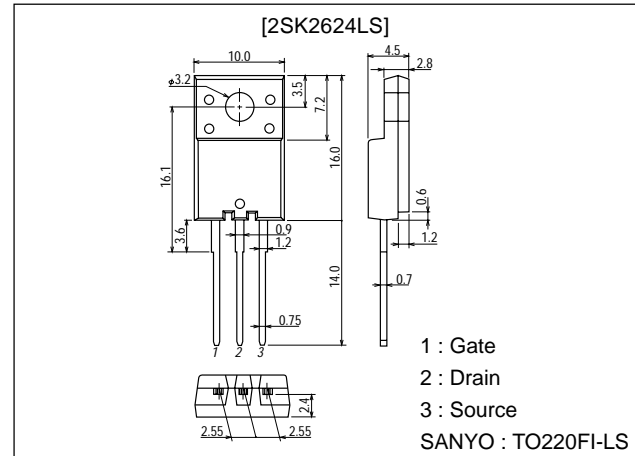
Features

- Low ON-resistance.
- Low Qg.

Package Dimensions

unit:mm

2078B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		600	V
Gate-to-Source Voltage	V_{GSS}		±30	V
Drain Current (DC)	I_D		3	A
Drain Current (Pulse)	I_{DP}		12	A
Allowable Power Dissipation	P_D	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	2.0	W
		$T_c = 25^\circ C$	25	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1mA$, $V_{GS} = 0$	600			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 600V$, $V_{GS} = 0$			1.0	mA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 30V$, $V_{DS} = 0$			±100	nA
Cutoff Voltage	$V_{GSS(off)}$	$V_{DS} = 10V$, $I_D = 1mA$	3.5		5.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 10V$, $I_D = 1.8A$	1.0	2.0		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$V_{GS} = 15V$, $I_D = 1.8A$		2.0	2.6	Ω
Input Capacitance	C_{iss}	$V_{DS} = 20V$, $f = 1MHz$		550		pF
Output Capacitance	C_{oss}	$V_{DS} = 20V$, $f = 1MHz$		165		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 20V$, $f = 1MHz$		85		pF

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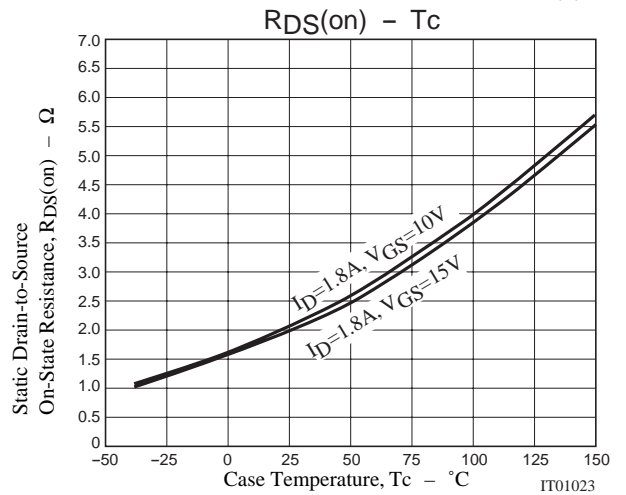
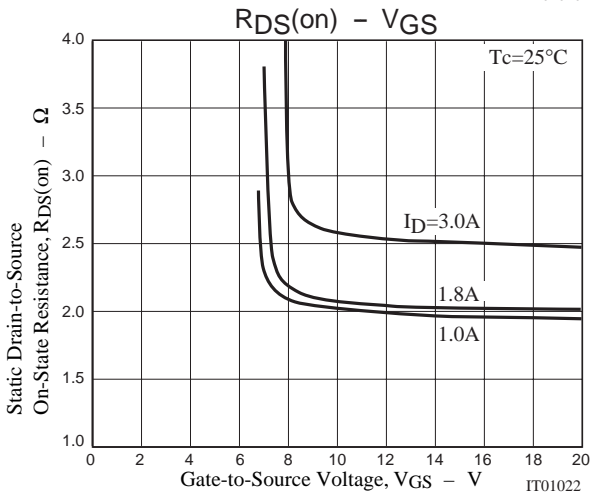
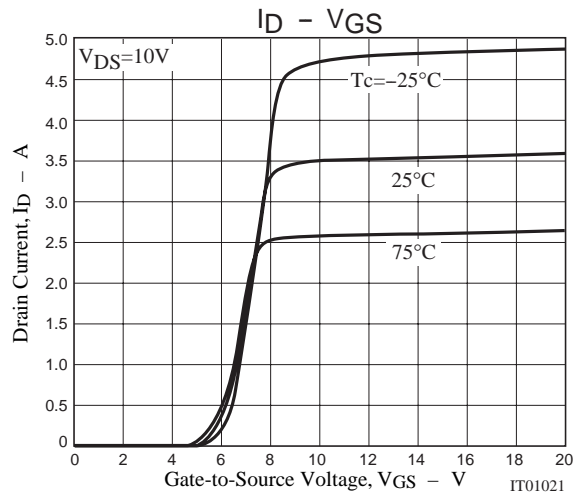
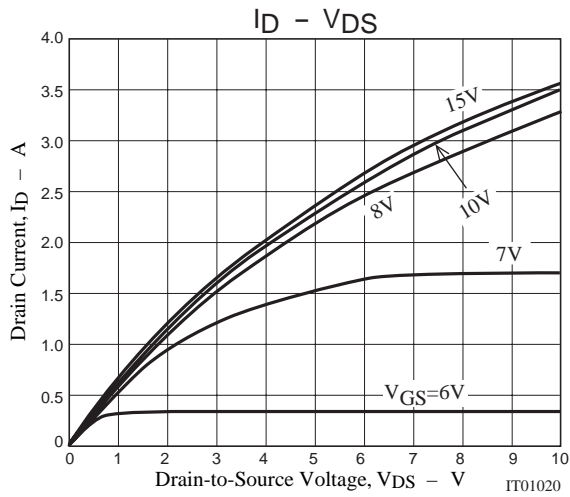
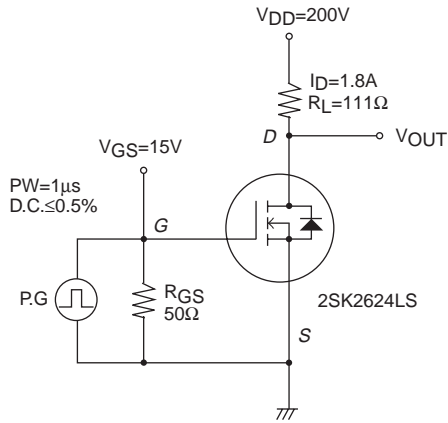
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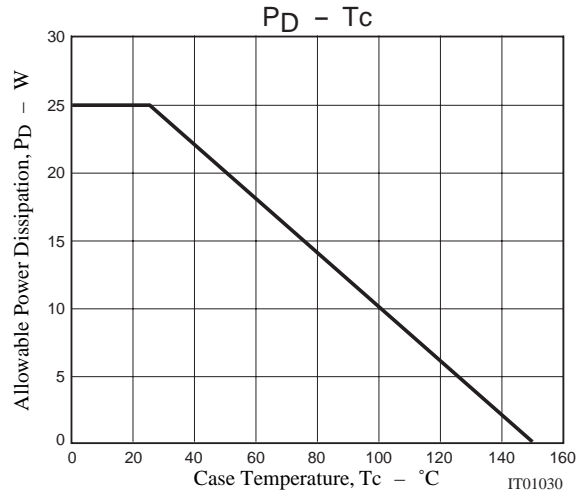
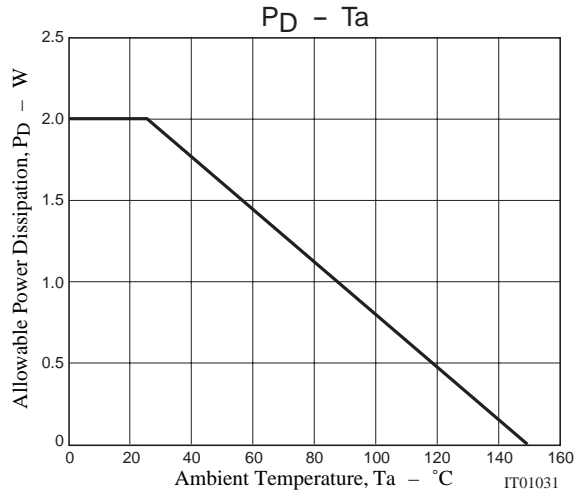
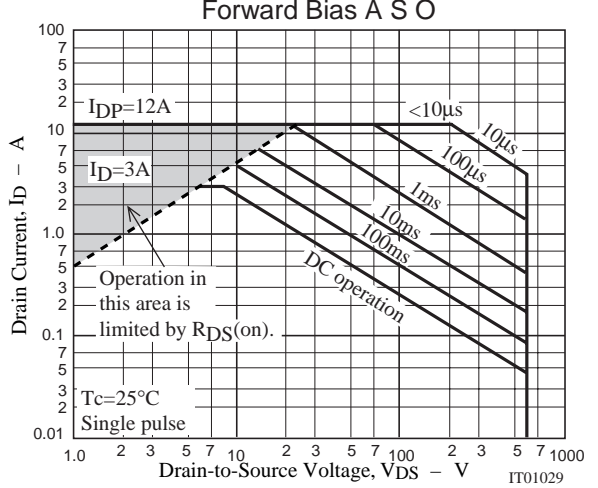
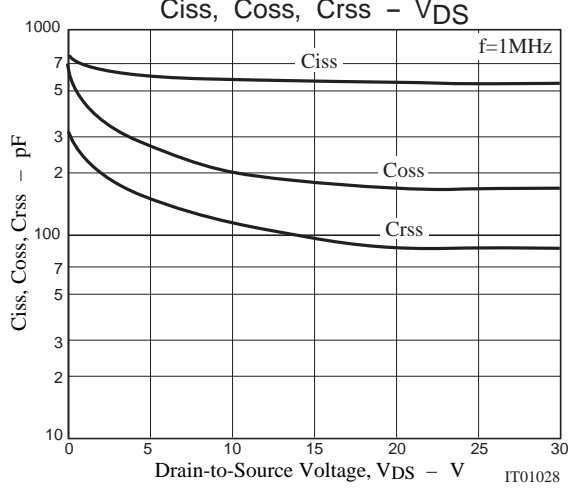
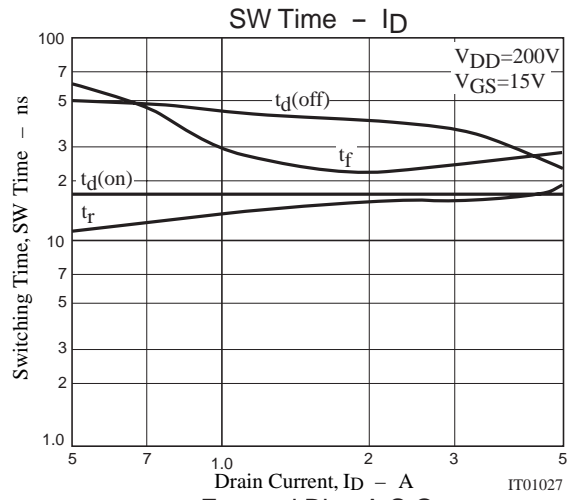
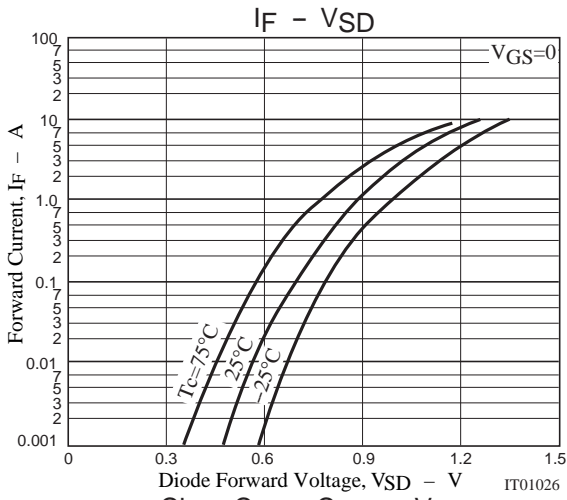
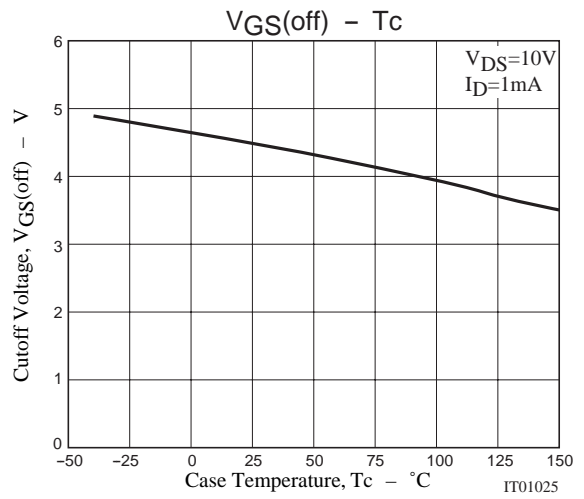
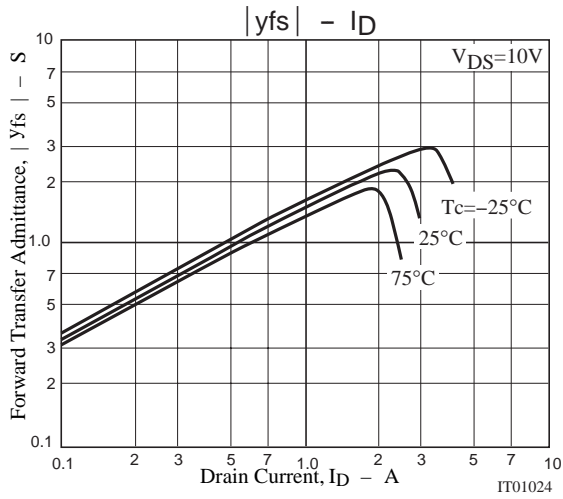
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	$V_{DS}=200V, V_{GS}=10V, I_D=3A$		15		nC
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		17		ns
Rise Time	t_r	See specified Test Circuit		17		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		40		ns
Fall Time	t_f	See specified Test Circuit		22		ns
Diode Forward Voltage	V_{SD}	$I_S=3A, V_{GS}=0$	0.98	1.2		V

Switching Time Test Circuit



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